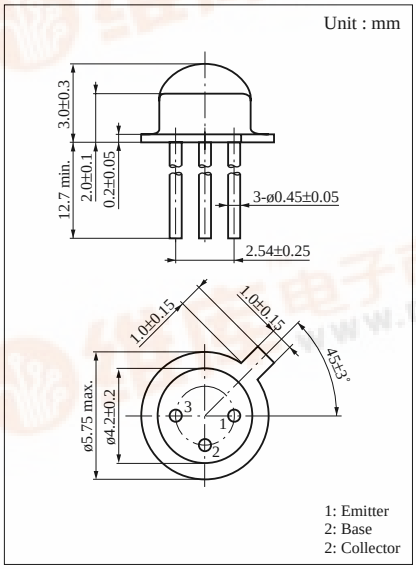
PNZ108CL (PN108CL)

Silicon NPN Phototransistor

For optical control systems



Features

- High sensitivity : $I_{CE(L)}$ = 3.5 mA (min.) (at L = 500 lx)
- Wide directional sensitivity for easy use
- Fast response : t_r = 5 µs (typ.)
- Signal mixing capability using base pin
- Small size (low in height) package

Absolute Maximum Ratings (Ta = 25˚C)

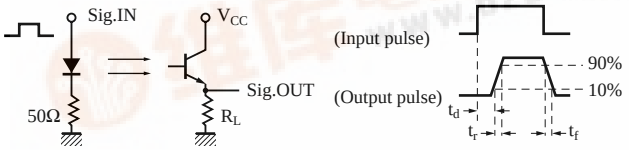
Parameter	Symbol	Ratings	Unit
Collector to emitter voltage	V_{CEO}	20	V
Collector to base voltage	V_{CBO}	30	V
Emitter to collector voltage	V_{ECO}	3	V
Emitter to base voltage	V_{EBO}	5	V
Collector current	I_C	20	mA
Collector power dissipation	P_C	100	mW
Operating ambient temperature	T_{opr}	–25 to +85	˚C
Storage temperature	T_{stg}	–30 to +100	˚C

Electro-Optical Characteristics (Ta = 25˚C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Dark current	I_{CEO}	V_{CE} = 10V		0.05	2	µA
Collector photo current	$I_{CE(L)}$ *3	V_{CE} = 10V, L = 500 lx*1	3.5	6		mA
Peak sensitivity wavelength	λ_P	V_{CE} = 10V		900		nm
Acceptance half angle	θ	Measured from the optical axis to the half power point		80		deg.
Rise time	t_r *2	V_{CC} = 10V, $I_{CE(L)}$ = 5mA		5		µs
Fall time	t_f *2	R_L = 100Ω		6		µs
Collector saturation voltage	$V_{CE(sat)}$	$I_{CE(L)}$ = 1mA, L = 1000 lx*1		0.3	0.6	V

*1 Measurements were made using a tungsten lamp (color temperature T = 2856K) as a light source.

*2 Switching time measurement circuit



t_d: Delay time
t_r: Rise time (Time required for the collector photo current to increase from 10% to 90% of its final value)
t_f: Fall time (Time required for the collector photo current to decrease from 90% to 10% of its initial value)

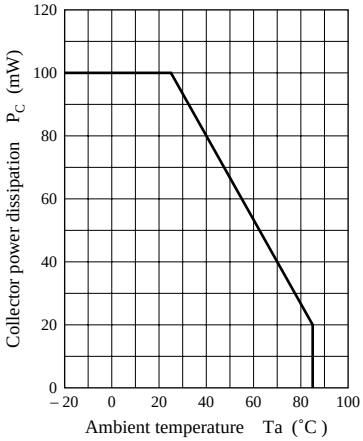
*3 $I_{CE(L)}$ Classifications

Class	Q	R	S
$I_{CE(L)}$ (mA)	3.5 to 6.0	5.0 to 9.1	> 7.5

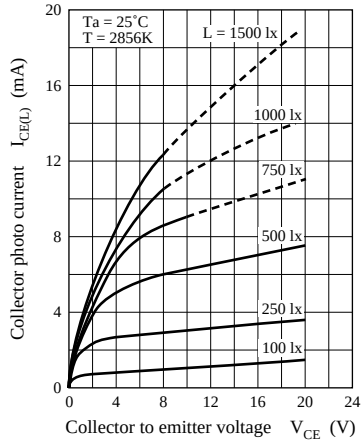
Note) Difficult to guarantee compliance with moisture resistance standard (MIL-STD-202D).

Note) The part number in the parenthesis shows conventional part number.

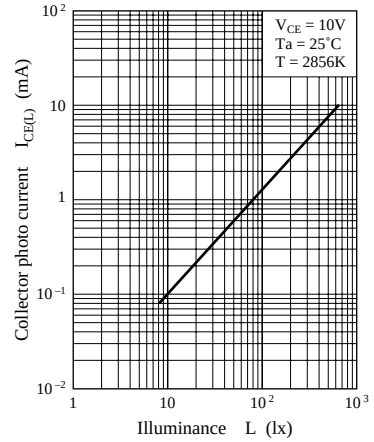
P_C — Ta



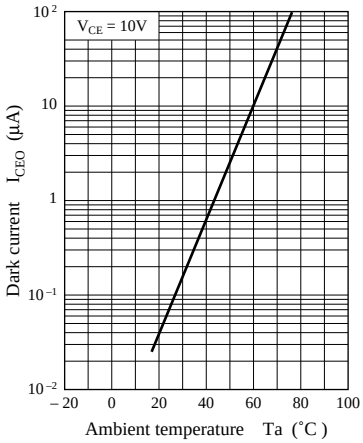
$I_{CE(L)}$ — V_{CE}



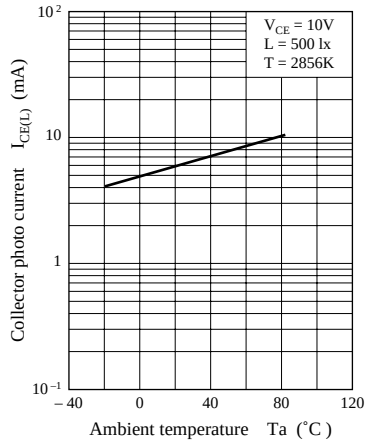
$I_{CE(L)}$ — L



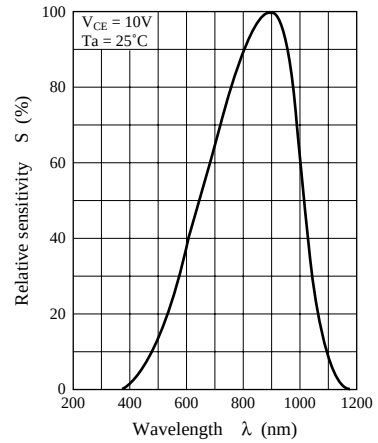
I_{CEO} — Ta



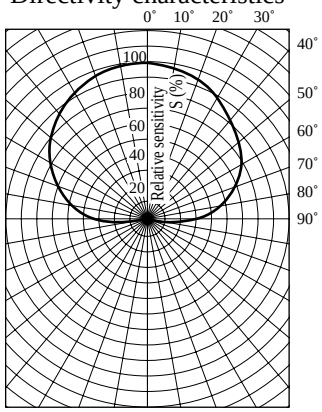
$I_{CE(L)}$ — Ta



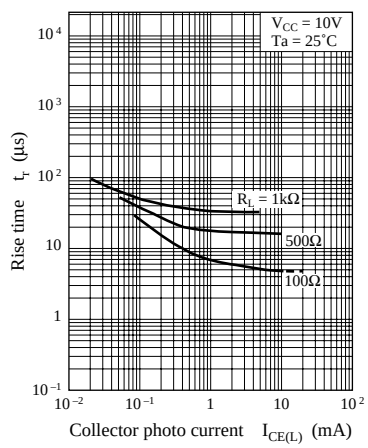
Spectral sensitivity characteristics



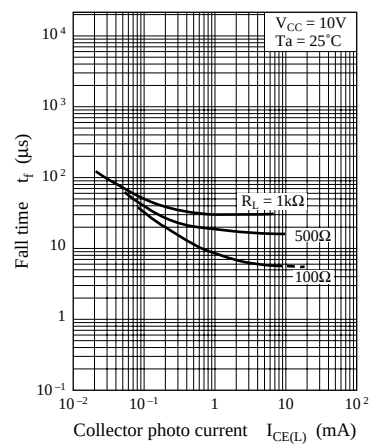
Directivity characteristics



t_r — $I_{CE(L)}$



t_f — $I_{CE(L)}$



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